



DONGGUAN XINGLIN ELECTRONICS CO.,LTD

SINGLE-PHASE SILICON BRIDGE RECTIFIER

KBP201 THRU KBP210

REVERSE VOLTAGE: 50 to 1000 VOLTS

FORWARD CURRENT: 2.0 AMPERE

FEATURES

- Reliable low cost construction utilizing molded plastic technique
- Ideal for printed circuit board
- Low forward voltage drop
- Low reverse leakage current
- High surge current capability

MECHANICAL DATA

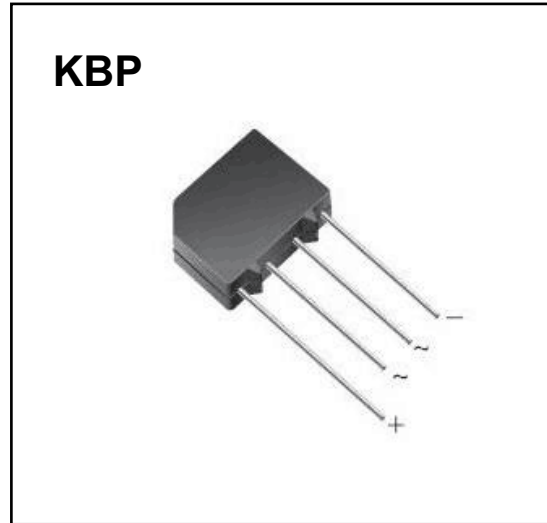
Case: Molded plastic, **KBP**

Epoxy: UL 94V-O rate flame retardant

Terminals: Leads solderable per MIL-STD-202, method 208 guaranteed

Mounting position: Any

Weight: 0.05 ounces , 1.42grams



Maximum Ratings and Electrical Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

	Symbols	KBP2005	KBP201	KBP202	KBP204	KBP206	KBP208	KBP210	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Current .375"(9.5mm) Lead Length at $T_A=50$	$I_{(AV)}$	2.0							Amp
Peak Forward Surge Current, 8.3ms single half-sine-wave superimposed on rated load (JEDEC method)	I_{FSM}	60							Amp
Maximum Forward Voltage at 3.0A DC and 25 °C	V_F	1.1							Volts
Maximum Reverse Current at $T_A=25$ at Rated DC Blocking Voltage $T_A=100$	I_R	5.0 100							uAmp
Typical Junction Capacitance (Note 1)	C_J	25							pF
Typical Thermal Resistance (Note 2)	R_{0JA}	30							/W
Typical Thermal Resistance (Note 2)	R_{0JL}	11							/W
Operating and Storage Temperature Range	T_J , T_{stg}	-55 to +150							

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Ratings and Characteristics Curves (TA = 25°C unless otherwise noted)

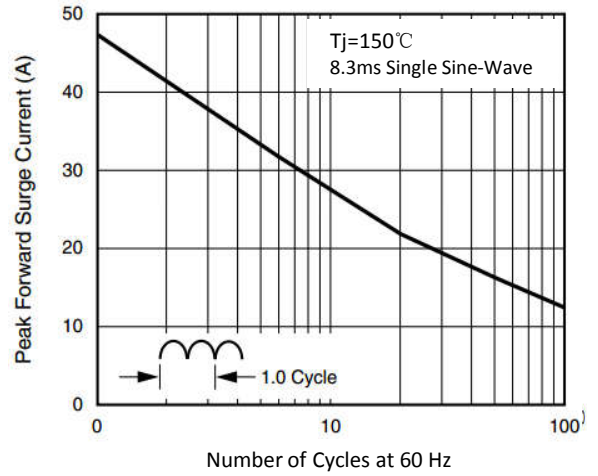
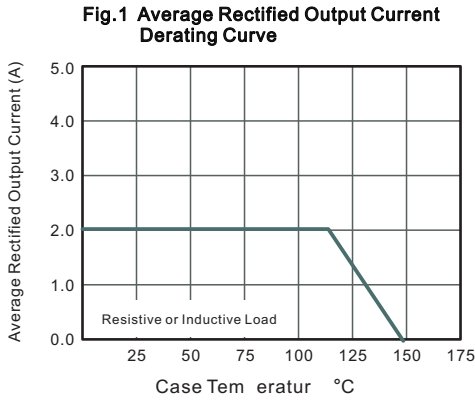


Fig. 2 - Derating Curve Output Rectified Current

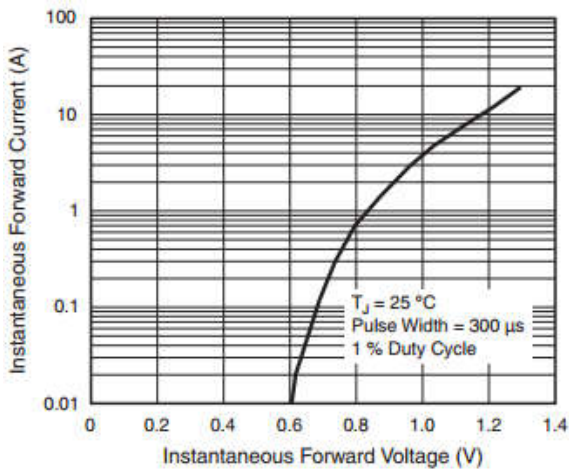


Fig. 3 - Typical Forward Characteristics Per Diode

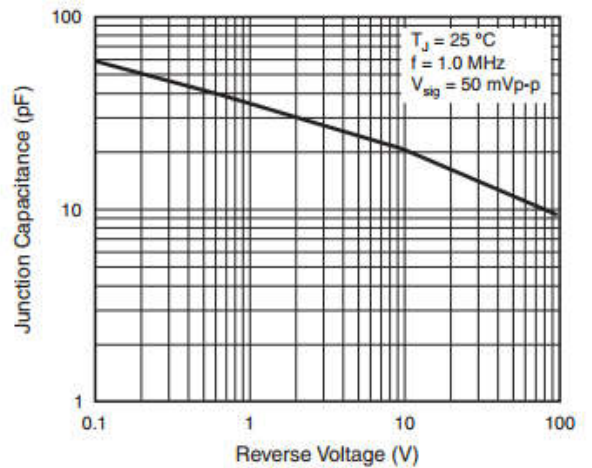
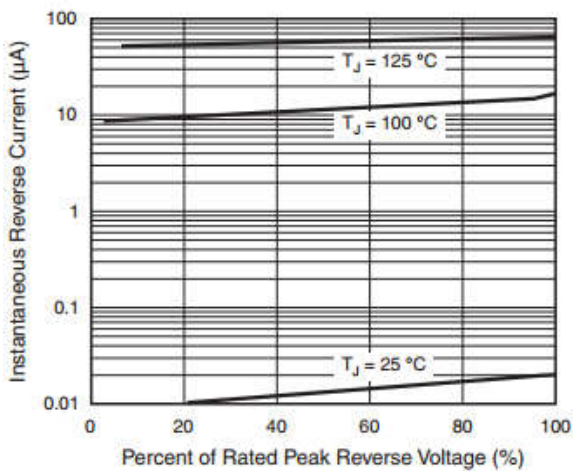


Fig. 5 - Typical Junction Capacitance Per Diode





Package: KBP

Dimensions in millimeters

